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We study analytically the M ott transition of the N-orbital Hubbard model using dynamical mean-eld theory and a low-energy projection onto an elective K ondo model. It is demonstrated that the critical interaction at which the insulator appears (U_{c1}) and the one at which the metal becomes unstable (U_{c2}) have different dependence on the number of orbitals as the latter becomes large: U_{c1} / N while U_{c2} / N. An exact analytical determ ination of the critical coupling U_{c2}=N is obtained in the large-N limit. The metallic solution close to this critical coupling has many similarities at low-energy with the results of slave boson approximations, to which a comparison is made. We also discuss how the critical temperature associated with the M ott critical endpoint depends on the number of orbitals.

I. IN TRODUCTION

The M ott transition is one of the central problem s in the eld of strongly correlated electronic system s. It is directly relevant to m any compounds, such as V_2O_3 , N iS_{2 x}Se_x [1], fullerenes [2], and two-dimensional organics of the BEDT family [3]. Viewed from a more general perspective, the M ott transition confronts us with the need to describe electrons in a solid in an intermediate coupling regime, where perturbative methods around either the localised or the itinerant limit are of very limited use. The M ott phenomenon is also a key issue for the development of electronic structure calculations of strongly correlated materials, a subject of current intense investigation [4].

A breakthrough in the understanding of this problem resulted from the development of dynamical mean-eld theory (DMFT) [5, 6, 7, 8]. Following the observation that a M ott transition as a function of the interaction strength U takes place in a (fully frustrated) oneband Hubbard model at half- lling [9] within DMFT, a rather surprising scenario was unravelled [10]. In the param eter space de ned by tem perature and interaction strength, two kinds of solutions of the DMFT equations were found, corresponding to an insulator and a metal, with a region $U_{c1}(T) < U < U_{c2}(T)$ in which both types of solution coexist. The spectral function of the insulating solution has only high-energy features corresponding to Hubbard bands, while the m etallic solution also has a low-energy quasiparticle resonance. Coexistence results rst-order phase transition at nite temperature. in a The rst order line ends into a second-order critical endpoint at T = $T_{\text{M II}}$, U = U_{\text{M II}} at which the coexistence domain closes (U_{c1} ($T_{M IT}$) = U_{c2} ($T_{M IT}$) = $U_{M IT}$). At T = 0, the transition is also second-order, because the metallic solution always has lower energy than the insulating one. A qualitative picture of the evolution of the spectral function as a function of control parameters was obtained, and this resulted in successful experim ental predictions [11].

Early work on these issues relied heavily on an accurate but approximate technique, the iterative perturbation theory [6, 10]. Later on, exact results near U_{c2} (T = 0) were obtained [12, 13], thanks to the developm ent of a renorm alization m ethod exploiting the separation of energy scales that holds true close to this critical coupling. Thism ethod performs a projection onto a low-energy effective theory after elim ination of the degrees of freedom corresponding to Hubbard bands. A clear picture of the structure of the DMFT equations near the Mott transition and of the di erent critical points was nally obtained through the introduction of a Landau functional approach [14]. These established results for the oneband Hubbard model together with num erical methods for solving DMFT equations, such as Quantum Monte Carlo [9, 15] and Num erical Renorm alization G roup [16], provide now a consistent picture of the M ott transition within DMFT.

In this paper, we investigate the M ott transition in the lim it of large orbital degeneracy, within DMFT.We establish analytically that the critical couplings U_{c1} (T = 0) and U_{c2} (T = 0) are not only di erent, but that they have very di erent scalings as a function of the number N of orbitals. Indeed, U_{c1} increases as N, while U_{c2} increases as N, so that the coexistence region widens. C lose to U_{c2} , the separation of scales which is at the heart of the projective m ethod becomes a symptotically exact for large N. This allows us to determ ine exactly the value of the critical coupling U_{c2} =N at large N, and also to demonstrate that slave-boson like approximations become a symptotically valid at low energy in this lim it. Finally, we discuss how the nite temperature m etal-

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insulator transition depends on the number of orbitals.

Our notings on the critical couplings are in agreement with early QMC results for the two-orbital model (N = 4) [21], and with recent results for higher values of N [22]. A widening of the coexistence window $[U_{\rm c1};U_{\rm c2}]$ as N increases is clearly seen in these simulations. A loo, for xed N, the critical coupling required to enter the M ott state is largest [18] at the particle-hole symmetric

lling n = 1=2. The present work also puts the results of Refs.[19, 20] in a new perspective: there, a $\stackrel{~}{N}$ scaling of the critical coupling was proposed. We indicate this indeed applies to the coupling where the insulator become substable (U_{c1}), while the true T = 0 M ott transition (at which the quasiparticle residue vanishes) takes place at U_{c2} / N. Indeed, in Ref.[19], the $\stackrel{~}{N}$ scaling was rationalized on the basis of a stability argument for the insulator. Finally, the rather high temperatures considered in [20] explain why only the $\stackrel{~}{N}$ dependence was reported there: distinguishing U_{c2} from U_{c1} requires signi cantly lower temperatures [22].

The lim it of large orbital degeneracy is relevant to the physics of systems with partially led d- or f- shells, as well as to fullerenes. Direct numerical approaches become prohibitively di cult as the number of orbital increases (QMC methods scale as a power law of N, while exact diagonalizations [17] scale exponentially). It is therefore important for future research to develop approximate but accurate impurity solvers which can handle many orbitals. The controlled results that we establish in this paper can be used as tests of these approximation methods.

II. MULTI-ORBITAL HUBBARD MODEL

W e consider a generalized H ubbard m odel involving N species of electrons, with H am iltonian:

where i; j are sites indices, the orbital index, e is the chem icalpotential and n the average density of particles per species :

$$n = \frac{1}{N} \frac{X}{h d_{i}^{y}} d_{i} i$$
 (2)

Introducing n in the H am iltonian is just a convention for the chem ical potential e. In particular, it is convenient at half-lling where the particle-hole symmetry in plies $n = \frac{1}{2}$ and e = 0. For a single site (atom), the spectrum consists of N + 1 levels, with energies $\frac{U}{2}$ (Q nN)² depending only on the total charge on the orbital: Q = 0; ;N and with degeneracies $\frac{N}{2}$.

The usual single-orb ital H ubbard m odel corresponds to N = 2 (= ";#). The H am iltonian considered here has a full SU (N) sym m etry which includes both spin and orbital degrees of freedom. Starting from a more realistic m odel which assumes an interaction matrix $U_{m\,m\,\circ}$ between opposite spins and $U_{m\,m\,\circ}$ J_{m m °} between parallel spins, it corresponds to the lim it of isotropic $U_{m\,m\,\circ} = U$ and vanishing H und's coupling $J_{m\,m\,\circ} = 0$.

W hen U is large enough, we expect a M ott insulating state to exist at llingsn = Q = N, corresponding to an integer occupancy of each site on average Q = 1; :N 1. In this paper, we investigate analytically the nature of these M ott transitions within DMFT.We consider only phases with no magnetic ordering and study the transition between a param agnetic m etal and a param agnetic M ott insulator. In Section III, we extract the large-N behaviour of U_{c1} and U_{c2} using the low -energy projective technique analysis of the DMFT equations introduced in [12] for N = 2 and extended in [23] : we show that the equations for the U_c's derived by this m ethod are greatly simplied for N! 1 in the sense that an atom ic limit becom es exact. In section IV, we nd quantitative agreem ent between these results and a multiorbital slave boson method. Finally, in Sec.V, we consider the Mott transition at nite tem perature.

III. LARGE-N BEHAVIOUR OF $U_{\,c1}$ AND $U_{\,c2}$

A. DMFT and the low energy projective m ethod

Let us recall brie y the DMFT equations and their low-energy projective analysis [12, 13]. DMFT maps the lattice H am iltonian above onto a multi-orbital Anderson in purity modelw ith the same local interaction term than in (1) and a hybridization function (i!_n). The local G reen's function reads: G_d (i!_n)¹ = i!_n + e (i!_n) d (i!_n). In this expression, e is the chemical potential (shifted by the H artree contribution) and d (i!_n) is a local self-energy. A self-consistency requirement is im - posed, which identi es G_d (i!_n) with the on-site G reen's function of the lattice model with the same self-energy d (i!_n). This reads:

$$G_{d}(i!_{n}) = {}^{Z} d" \frac{D(")}{i!_{n} + e_{d}(i!_{n})}$$
(3)

In this expression, D (") is the free electron density of state (d.o.s.) corresponding to the Fourier transform of the hopping matrix elements t_{ij} . In the particular case of a sem i-circular d.o.s. with halfwidth D = 2t, equation (3) simpli esto:

$$(i!_n) = t^2 G_d (i!_n)$$
 (4)

Solving the impurity model subject to (3) determines both the hybridization function and the local G reen's function in a self-consistent manner. In order to give an explicit H am iltonian form to the Anderson impurity m odel, the function $% \mathcal{V}_{k}$ can be represented with an auxiliary bath of conduction electrons c_k , with e ective single-particle energies $_k$ and e ective hybridizations V_k to the local orbital such that :

$$(i!) \qquad \begin{array}{c} X \\ \underbrace{\mathbf{y}_k \mathbf{f}}_{i! \ k} \end{array} \tag{5}$$

$$H = \frac{X}{k} c_{k;}^{y} c_{k;} + \frac{X^{k}}{V_{k}} V_{k} (c_{k;}^{y} d + d^{y} c_{k;})$$

$$K = \frac{X}{d^{y} d} + \frac{U}{2} X (d^{y} d - n)$$
(6)

W ithin DMFT, the M ott transition at U_{c2} and T = 0is associated with a separation of energy scales. For U slightly smaller than U_{c2} , the d-electron spectral function has a sharp quasiparticle peak, well separated from the high-energy Hubbard bands. Naturally, a small amount of spectral weight does connect these two features in the m etal. Slightly above U_{c2} , the M ott gap $_g$ separating the Hubbard bands of the insulating solution is nite. W hile the weight Z of the quasiparticle peak vanishes at U_{c2} , the M ott gap $_g$ disappears only at the smaller critical coupling U_{c1} . Because of the self-consistency condition (3), the hybridization function of the e ective conduction bath (and hence the $_k$'s) also displays this separation of scales.

This remark led the authors of R ef. [12] to use a projective m ethod in order to study the critical behaviour at U_{c2}. W ithin this approach, the e ective conduction electron bath is separated into a high energy sector (k 2 H) associated w ith the upper (H⁺) and lower (H) Hubbard bands, and a low energy sector (k 2 L) associated w ith the quasiparticle resonance. The in purity m odel H am iltonian is thus written as (for sim plicity we take V_L and V_H independent of k):

$$H = H_{L} + H_{H} + H_{HL}$$
(7a)

$$H_{L} = {}_{k} C_{k;}^{y} Q_{k;}$$
(7b)

$$H_{H} = \begin{matrix} X & h & i \\ X & h & k \\ & & k c_{k}^{y}, c_{k}, + V_{H} c_{k}^{y}, d + h c \\ & & &$$

$$H_{HL} = V_{L}c_{k;}^{V}d + hc:$$
 (7d)

We note that the self-consistency condition (3) in plies that $V_L^2 = t^2$ is proportional to the quasi-particle residue Z, so that it is clear that the low-energy hybridization vanishes at U_{c2} .

In order to obtain an e ective theory close to U_{c2} , one rst diagonalizes the high-energy part H_H of the H am iltonian, and obtains an e ective low-energy ham iltonian by expanding in V_L . From the presence of a nite gap in the high-energy bath $_{\rm k}$ (for k 2 H), H $_{\rm H}$ describes an in purity in a sem iconducting bath. The position of the d-level (i.e. the chem ical potential) xes the number of electrons in the ground-state. For a charge Q = nN, this high-energy problem has a $_{\rm Q}^{\rm N}$ degenerate ground-state, spanned by eigenvectors j i (w ith eigen-energy E $_{\rm gs}$). The detailed form of these states is com plicated (they m ix w ith higher in purity charge states through V_{\rm H}), but they form a representation of the SU (N) \spin" group, of dimension $_{\rm Q}^{\rm N}$.

U sing a generalized Schrie er-W ol (SW) transform ation to order V_L^2 in order to project onto the low -energy H ilbert space (de ned by the selected charge sector of the impurity d, and the low -energy sector for the conduction bath k 2 L), one obtains an elective K ondo H am iltonian [12, 13, 23]:

$$H_{e} = \frac{X}{k^{2}L;} k^{V}c^{V}_{k}; q_{k}; + \frac{V^{2}_{L}}{U} K^{V}k^{0}; ; {}^{0}X C^{V}_{k}; q_{k^{0}}; o$$
(8)

where X j ih j is a Hubbard operator connecting two states in the ground state manifold. The Ham iltonian contains potential scattering terms for $= {}^{0}$ and spin- ip (K ondo) terms for $\in {}^{0}$, with the spin operator S = X X. The matrix of (dimensionless) coupling constants reads [13, 23]:

$$J \stackrel{\circ}{\longrightarrow} d^{y} \stackrel{U}{\underset{H_{H}}{\longrightarrow} E_{gs}} d \qquad d \frac{U}{\underset{H_{H}}{\longrightarrow} E_{gs}} d^{y} \stackrel{V}{\underset{gs}{\longrightarrow}} d^{y} \stackrel{(9)}{\underset{gs}{\longrightarrow}} d^{y} \stackrel{(9)}{\underset{gs}{$$

W e em phasize that the low -energy H am iltonian has been derived to st order in V_L^2 : this is asymptotically justi ed exactly at the critical point (and hence su cient to determ ine the critical coupling), but deviations away from the critical point require to consider higher order terms in V_L . Finally, we note that the bandwidth of this K ondo problem is of order Z t, while the coupling is of order V_L^2 =U Z t²=U. Hence, the dimensionless coupling constant of the elective low -energy K ondo problem is of order one: we have an intermediate coupling K ondo problem [14].

The conditions that determ ine U_{c1} and U_{c2} have been derived within the projective method [12, 23] and within the more general Landau functional approach [14] (in which the stability of the insulating solution to di erent kinds of low energy perturbations is studied using a Landau functional of the hybridization function (i!_n)). The condition for U_{c2} reads:

$$\frac{U_{c2}^{2}}{t^{2}} = \begin{array}{c} X & N & {}^{1} \\ & & N & J & J \end{array}$$
(10)
+ X c^yc J J J J

As explained in [14, 23], an analogous equation is found for U_{c1} , where o -diagonal terms in the average are taken

to zero. For nite N, this equation is complicated to solve, since the average on the right-hand side is a function of J which we can only obtain by solving the low energy K ondo problem explicitly. However, we will show in the following that:

- 1. Using the SU (N) symmetry, the tensor structure of J can be parametrized with only two numbers A and B, which are dimensionless functions of N, n, and $V_H = U$. This greatly simplifies (10) (Section IIIB).
- 2. An explicit calculation of A and B can be performed in the atom ic lim it $V_H = 0$. This allows us to show that the two critical couplings have the following N -dependence at large N:

In fact, the atom ic lim it evaluation of A and B becomes asymptotically exact when U is taken to be proportional to N. This is not the case when U / \overline{N} , but we show that corrections to the atom ic lim it do not modify the scaling (11a).

3. For U / N, the e ective K ondo problem can actually be solved explicitly at large N, using standard techniques. This allows for an explicit computation of the matrix element X c^y c involved in (10). Since, from the above remark, the e ective couplings entering the K ondo problem can be evaluated in the atom ic limit in that case, this allows us to determ ine the prefactor \mathfrak{G}_{c2} exactly (Sec. IIID). Because the atom ic limit is not asymptotically exact for U / N, we are not able to obtain an exact determ ination of \mathfrak{G}_{c1} .

B. Sim plication due to the SU (N) sym m etry

C om puting the couplings (9) is a complicated task in general, since it requires a know ledge of the states j i; j i, and thus a diagonalization of H_H. However, general considerations based on the SU (N) symmetry of the model allow one to reduce the unknown K ondo couplings J ⁰ to two dimensionless numbers only. Let us consider the operator:

$$O_{1}^{\circ} d \frac{1}{H_{H} E_{gs}} d^{y}_{\circ}$$
 (12)

Since the Ham iltonian is SU (N) symmetric, this operator transforms under SU (N) with the representation F = F = id ad : the tensor product of the fundamental F (one box in the Young tableau language) and its complex conjugate F (N 1 boxes), which reduces to the sum of the identity id and the adjoint ad. If we denote by R the ground state representation (a column with Q = nN boxes), the tensor structure of J is then given by the W igner-Eckart theorem : we have to nd the occurence of R in (id ad) R. We have a trivial term id R = R and a single non trivial one since ad R = R :::, where ::: denotes other irreducible representations. Then we have :

$$d \frac{1}{H_{H} E_{gs}} d^{y}{}_{_{0}} = A_{1} \circ + B_{1}C^{\circ}$$
(13)

where C are the C lebsch-G ordan coe cients hR jad R i.

In order to avoid the computation of C, we can use the following argument. Let us consider the operator d d^{y}_{0} , which has the same symmetry as O_{1} , so the previous symmetry argument gives

$$d d^{y}_{0} = A_{2} + B_{2}C^{0}$$
 (14)

with the same C, but di errent ∞ cients A_2 ; B_2 . Since (11b) $B_2 \notin 0$, we can eliminate C between the two equations. We nally obtain the general form, valid to rst order in V_t^2 for a SU (N) symmetric model:

D

$$J \stackrel{0}{=} A \stackrel{0}{=} H \stackrel{$$

In this expression, A (N;n;V_H=U) and B (N;n;V_H=U) are dimensionless coe cients which depend only on the dimensionless ratio V_H =U associated with the high-energy problem (and of course a priori also on orbital number N and density n).

Inserting (15) into equation (10), we obtain the sim plied form of the conditions which determ ine the critical couplings:

$$\frac{U_{c1}^{2}}{t^{2}} = (A + nB)^{2} + B^{2}n(1 n)(N + 1)$$
(16a)

$$\frac{U_{c2}^{2}}{t^{2}} = (A + nB)^{2} + B^{2}n(1 n)(N + 1)$$

$$B^{2} S \circ C_{o}^{y}c$$
(16b)

C. The atom ic lim it

The atom ic lim it approximation is dened by $V_{i} = 0$. In this lim it, the states j i are just the inpurity states $j i_0 j_1 _{Q} i (Q = 0; ;N)$, without mixing with the high-energy electron sector. In that case, A and B (from (15)) can be computed explicitly (we choose here e = 0, i.e. the chemical potential is bound to be at the center of a step in the C oulom b staircase). We nd:

$$A = 2; B = 4$$
 (17)

We note that these coe cients do not depend on N in the atom ic limit. Moreover, it is clear that, in general (for an explicit proof, see Sec.IIID):

$$\begin{array}{ccc} X & D & E \\ S & \circ C^{Y} \circ C & / N^{2} \end{array}$$
(18)

W hen using these results into (16a-16b), we obtain the N-dependence of the critical couplings quoted in (11a-11b).

This derivation relies on the use of the atom ic lim it $V_{\rm H}$ = 0. An important question is therefore to check that the N -dependence of the critical couplings is not modi-

ed by the interaction V_{H} that dresses the atom ic states j i. W e exam ine carefully this question in Appendix A, where we give an explicit proof that this is indeed the case. The problem is in fact quite di erent for U_{c1} and U_{c2} . For the latter, U must be scaled as U = N \mathcal{G} . In that case, we show in the appendix that the atom ic lim it calculation of A and B is in fact exact at large N. This can be expected since the band gap diverges with N, so that the Hubbard bands are well separated from the low energy degrees of freedom . However, one m ight worry that the growing number of orbitals (N) could counterbalance this e ect. This is actually not the case, and we show that the corrections to J (or A $_{H}$ B) coming from V_{H} are subdom inant in large-N, order by order in perturbation theory. M oreover, the low -energy e ective K ondo problem becomes exactly solvable when U / N (i.e close to U_{c2}): this is the subject of the next section (Sec. IIID), in which the exact value of the prefactor \mathfrak{G}_{c2} is obtained.

The problem is more involved for U_{c1} , corresponding to the scaling U / N. In that case, corrections in V_H beyond the atom ic lim it do produce corrections to A and B (hence to J). However, we are able to show (Sec. A 2 of the appendix) that these corrections are of order one, so that the scaling $U_{c1} = N \ \ensuremath{\mathfrak{G}_{c1}}$ does hold.

D . Explicit large-N solution of the e ective low energy K ondo problem at $U_{\rm c2}$

In this section, we explicitly solve the low energy e ective K ondo problem in the large-N lim it using standard m ethods [26], in order to obtain the prefactor \mathfrak{G}_{c2} . The e ective H am iltonian (8) reduces at order $(1=N^2)$ to:

$$H_{e} = \frac{X}{{}_{k}c_{k}^{y}, q_{k};} \qquad (19)$$

$$+ \frac{4V_{L}^{2}}{N \mathfrak{F}} \frac{X}{{}_{k}{}_{k}{}^{o}{}_{2}{}_{L};} \quad f_{0}^{y}f = \frac{\circ}{2} c_{k}^{y}, q_{k}{}^{o}{}_{;} \circ$$

This model becomes exactly solvable at large N because the K ondo coupling scales as 1=N (which is a result of U / N b. Introducing an auxiliary boson eld b conjugate to $_{k} f^{y}c_{k}$, and a Lagrange multiplier eld to enforce the constraint $f^{y}f = Nn$, we see that, as N ! 1, the eld b undergoes a Bose condensation, and the saddle-point values of the b; elds are determined by the equations (at T = 0):

$$G_{f}^{1}(!) = ! + b^{2} G_{cL}^{0}(!)$$
 (20a)

$$n = -\frac{1}{2} d! \text{ Im } G_{f}(!)$$
 (20b)

$$\frac{\mathfrak{G}_{c2}}{4V_{L}^{2}} = \begin{array}{c} 2 \\ d \\ G_{f} \\ (\\)G_{cL}^{0} \\ (\\) = \frac{1}{2} \begin{array}{c} 2 \\ 0 \\ 1 \end{array} d! \text{ Im } [G_{f} \\ (\\)G_{cL}^{0} \\ (\\)]$$
(20c)

In this expression, G_{cL}^{0} denotes the G reen's function of the low-energy part of the e ective bath of conduction electrons, in the absence of K ondo coupling, namely:

$$G_{cL}^{0}(i!) = \frac{X}{k^{2}L} \frac{1}{i!} = \frac{1}{V_{L}^{2}} L(i!)$$
(21)

First we express the self-consistency condition (3) or more precisely its low-energy counterpart. We relate the low-energy part of the on-site G meen's function, G_{dL} (i!_n), to the auxiliary-ferm ion one, G_f (i!_n), by in – posing that the low-energy part of the interacting G meen's function of the e ective bath of conduction electrons, G_{cL}, can be calculated either from the original Anderson m odel or from the low-energy projected K ondo m odel, with identical results. G_{cL} is related to G⁰_{cL} through the conduction electron T -m atrix:

$$G_{cL} = G_{cL}^{0} + (G_{cL}^{0})^2 T$$
 (22)

The Anderson m odel T -m atrix is $V_L^2 G_{dL}$, while it is $b^2 G_f$ for the low-energy K ondo m odel. Therefore G_{dL} is directly related to G_f by:

$$V_{\rm L}^{2} G_{\rm dL} = b^{2} G_{\rm f}$$
 T (23)

U sing this into Eq.(20a), one nds the expression of G_{dL} in terms of the low-energy hybridization $_{L}$:

$$G_{dL}^{1}(i!_{n}) = \frac{1}{Z}(i!_{n} +) L(i!_{n})$$
 (24)

where we have introduced the notation:

$$Z = \frac{b^2}{V_L^2}$$
(25)

We can nally obtain G_{dL} in closed form by making use of (24) into the self-consistency condition (3) (restricted to the low-energy sector). This yields:

$$G_{dL}(i!) = \frac{Z}{L(i!) + G_{dL}^{-1}(i!)}$$
(26)

$$d'' \frac{D('')}{\frac{1}{2}(i! +)}$$
(27)

The low-energy part of the local spectral density reads:

$$_{dL}$$
 (!) $\frac{1}{2}$ Im G $_{dL}$ (! + i0⁺) = D $\frac{!+}{Z}$ (28)

By comparing this form of G_{dL} to its expression in terms of the local self-energy, we recognize that Z is the quasiparticle weight and yields the zero-frequency limit of d:

$$_{d}(0) = \frac{1}{Z}$$
; $Z = 1$ $\frac{\dot{\theta}_{d}}{\dot{\theta}!} \dot{j}_{=0}$ (29)

The value of =Z can be determined by using the explicit form of $_{d}$ = Z $_{f}$ into (20b):

$$n = \int_{1}^{Z_{0}} d! \frac{1}{Z} D \frac{! +}{Z}$$
(30)

Changing variables, this leads to $=Z = _0 (n)$ where $_0 (n)$ is the non-interacting value of the chem ical potential, de ned by:

$$n = \int_{1}^{Z} d'' D ('')$$
(31)

W e note that this is precisely the result expected from Luttinger's theorem (we have $_{\rm d}(0) = _{\rm 0}(n)$ which insures that the Ferm i surface volume is unchanged by interactions). Hence, the low-energy part of the spectral function (quasi-particle resonance) is simply given by:

$$_{dL}$$
 (!) = D $\frac{!}{Z}$ + $_{0}$ (n) (32)

Its shape is simply given by the non-interacting d.o.s., centered at ! = $\rm~Z_{-0}$ and with a width renorm alized by Z .

Second, we can now use (20c) and Im [$_{\rm L}G_{\rm f}$] = $\frac{!+}{Z}$ Im $G_{\rm f}$, to obtain :

$$\frac{\mathfrak{G}_{c2}}{4} = \frac{1}{Z_{c}^{2}} d! (! +)_{dL} (!)$$
(33)

$$= \frac{2}{1} \frac{0}{Z} \frac{d!}{Z} \frac{!+}{Z} D \frac{!+}{Z}$$
(34)

C learly, Z drops out of this equation, which has therefore a unique solution, the critical coupling \mathfrak{G}_{c2} at which Z vanishes. This is expected: the low-energy e ective H am iltonian is valid only exactly at the critical point. A determ ination of the critical behaviour of Z slightly away from the critical point would require considering higherorder terms in the e ective low-energy H am iltonian. W e therefore obtain the large-N value of the critical coupling (using the expression of =Z found above):

with:

$$z_{0(n)}$$

"0(n) d""D(") (36)

This result is rem in iscent of the critical coupling obtained in the Gutzwiller or slave-boson methods [24]: a detailed comparison is made in Sec.IV. Taking for example a rectangular d.o.s. of half-width D, Eq.(35) yields:

$$\frac{U_{c2}}{N} = 4D n (1 n)$$
 (37)

 \mathfrak{F}_{c2} is largest at half-lling (n = 1=2). This is because orbital uctuations are maximum there, so that it is more di cult to destroy the metallic phase (see how ever [18]). O by iously, for nite N, a M ott transition is found only for rational values of n = Q=N with integer Q (these values are dense on the interval [0;1] as N becomes large).

A nother way to obtain U_{c2} is to use the criterion of section IIIC together with the present large N limit in order to compute the matrix element ${}^{P}_{0}$ S ${}_{0}c^{y}{}_{0}c$. This can be exactly evaluated at N = 1 using the elective action for the K ondo m odel (20):

$$S_{e} = \begin{matrix} Z & X & X \\ d & f^{y} \emptyset f & (f^{y} f n) \end{matrix} (38)$$

$$+ \begin{matrix} Z \\ d & \frac{N \, \textcircled{P}}{4V_{L}^{2}} b^{2} + \begin{matrix} X \\ bf^{y} c + bc^{y} f \end{matrix}$$

$$Z & Z & X \\ d & d^{0} & c^{y} ()G_{cL}^{0} (0)^{-1} c (0) \end{matrix}$$

Because this action is gaussian, it is straightforward to get the following average (here \in ⁰):

We nd therefore:

$$X D E Z^{2} O C^{0} C = N^{2}b^{2} d G_{f} ()G^{0}_{cL} ()^{2} + O(N)$$

$$(40)$$

which indeed scales as N 2 . Inserting this into (16b), we have :

$$U_{c2} = 4t \frac{V_L}{Zt} N b d G_f ()G_{cL}^0 ()$$
 (41)

which coincides with Eq. (20c) since $p_{\overline{Z}} = b=V_L$. Hence, we have checked that both m ethods (explicit large-N solution and projective criterion of Sec.IIIC) yield the same result for the critical interaction U_{c2} .

IV. COM PAR ISON TO A SLAVE-BOSON APPROACH

In this section, we show that a multiorbital slave boson approximation reproduces the previous results close to the critical coupling $U_{\,\rm c2}$. This method is an extension to many orbitals of the Gutzwiller approximation, formulated in terms of slave bosons by Kotliar and Ruckenstein [27] and extended to many orbitals in [28]. Indeed, with the scaling $U = N \oplus$, the M ott gap is of order N and quasiparticles dom inate the physics over most of the energy range. Furtherm ore, the expression (28) for the physical spectral function close to U_{c2} contains precisely the same ingredients than in slave boson m ethods, namely: a shift of the e ective level which insures Luttinger's theorem, and a quasiparticle weight Z (vanishing at the transition). The self-energy contains no further renorm alizations (in particular the quasi-particle lifetim e is in nite). This bare-bone picture of a strongly correlated Ferm i liquid is precisely that emphasized by slave boson approaches.

Following [28], one introduces 2^N slave bosons $\lim_{p \to \infty} associated with a given spin conguration <math>1$ p on the impurity orbital. The probability that the orbital is in a given spin conguration is simply given by $h_{1}^{Y} \lim_{p \to \infty} 1 \lim_{p \to \infty} 1$. The physical electron operator is represented as:

$$d^{y} = z f^{y}$$
(42)

with:
0 1
z
$$g_1 e^{\sum_{p \neq (1; \dots; p)} y}$$
 1
2 $g_1 e^{p \neq (1; \dots; p)}$ 3 g_2 (43)
2 $g_1 = \sum_{p \neq (1; \dots; p)} y$ 3 g_2 (43)
2 $g_1 = \sum_{p \neq (1; \dots; p)} y$ 3 $g_1 = 2$
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This representation is supplemented by two constraints:

$$f^{y}f = \begin{array}{c} X & X \\ & y \\ & & 1 \\$$

$$1 = \begin{array}{c} X & X \\ P & (1,1) + P \\ X & X \\ P & (1,1) + P \\ P & (1,1) + P \end{array}$$
(44b)

At this stage, this is an exact representation of the H ilbert space, which can be used to rewrite the H ubbard H am iltonian. In order to obtain an approximate solution, we shall assume that all auxiliary bosons undergo a B ose-condensation, ie become static c-numbers, and that furtherm ore the corresponding expectation value depends only on the total charge p and not on the species spin con guration
$$_1$$
; $_p$; W e shall thus set, at each site:

$$i_1 \dots i_p = p$$
 (45)

W e emphasize that this approximation does not correspond to a controlled saddle-point, even in the large-N $\lim i t$, since the number of auxiliary % f(t) = 0 elds grows rapidly with N .

U sing this Ansatz, the Hubbard Ham iltonian can be rewritten in the form :

$$H = \begin{pmatrix} X & X^{N} \\ & & \\ i_{j}j = 1 \end{pmatrix} t_{ij}z^{2} f_{i}^{Y} f_{j} + \frac{U}{2} \begin{pmatrix} X & X^{N} & N \\ & & \\ & p \end{pmatrix} p^{2} (p N n)^{2}$$
(46)

with:

$$z = \frac{1}{p (1 n)} \sum_{p=0}^{N 1} N 1$$
 (47)

and the constraints:

$$X^{N}$$
 N 1 $_{p}^{2}$ = n hf^yfi (49)

The free-energy corresponding to this H am iltonian m ust then be m inim ized with respect to the N + 1 variational parameters $_{p}$'s, subject to the two constraints above. In the following, we brie y outline this procedure, focusing for simplicity on the half-led case (n = 1=2) at zero-tem perature.

In this case, particle-hole sym m etry m akes the analysis simpler. It implies that p = N p, and it can then be shown that the constraint P = N p + 1 p

$$\frac{1}{N}E_{0} = 4 "_{0} "X^{1} N 1 = p 0 p p p p + 1 + \frac{2}{2} \frac{X^{N} N}{p 0} p p p 2 p (50)$$

with $"_0$ the (absolute value) of the non-interacting kinetic energy per orbital (as de ned in (36)), and @U=N, as de ned above.

It is clear from the Ham iltonian (46) that this slaveboson approximation leads to a picture of quasiparticles with no residual interactions. The quasiparticle weight reads:

$$Z = z^{2} = \frac{1}{n(1 - n)} \int_{p=0}^{N_{X} - 1} N = \frac{1}{p + 1}$$
(51)

while the chemical potential shift in the previous section corresponds in the present context to the Lagrange multiplier associated with the constraint (44a) (it vanishes at half-lling).

W e also note that the non-interacting lim it is correctly reproduced, thanks to the square-root norm alization factors [27] introduced in (43). In that lim it, Z = 1 and $E_0 = N "_0$.

In order to analyze the M ott transition, we note that within this approach, an insulating solution can be found for arbitrary strength of the coupling U. It corresponds to the trivial solution:

$${}^{2}_{N=2} = {}^{N}_{N=2} {}^{1}$$
; $p = 0$ (p $\in \frac{N}{2}$) (52)

which yields the T = 0 occupancies in the atom ic limit. This solution is always an extrem um of the variational energy (corresponding to a boundary), but not always a minimum. Indeed, a minimum with a lower energy exists for $\mathfrak{F} < \mathfrak{F}_{c2}$. To nd this critical coupling, we perturb around the trivial solution. Close to U_{c2} , only the occupancies of the states with charge N =2 1 m atter, and we set: ${}_{N=2}^{2} = {}_{N=2}^{N-1} + {}_{N=2-1} = {}_{n}$ and ${}_{p}$ = otherwise (where ()) denote terms can be neglected). The energy di erence with the trivial insulating solution reads:

$$E = 4"_{0} \frac{\prod_{N=2}^{N-1} + \prod_{N=2-1}^{N-1}}{\prod_{N=2}^{N}} 2$$

$$+ \frac{19}{2} N + N = 2 1 + N = 2 + 1$$
(53)

H ence, the critical coupling at which the m etallic solution disappears reads:

$$\mathfrak{G}_{c2} = 16 "_0 \frac{\frac{N}{N-2}}{\frac{N}{N-2}} = 4 "_0 \frac{N+2}{N}$$
(54)

This value coincides with that obtained by Lu [24] using the G utzw iller approximation. Remarkably, it agrees with our exact result in the N ! 1 limit. Together with the considerations above, this suggests that such a slave boson approach becomes asymptotically exact, at low energy and close to the critical coupling U_{c2} , in this limit. This estimate of the critical coupling is already quite accurate for the smallest value of N = 2 (we take for reference a semi-circular band with half-width D = 1):

$$U_{c}(N = 2) = \frac{8D}{3}(N + 2)' 3:3$$
 (55)

(the NRG and the projective analysis of the one-orbital m odel indicate that U_c is very close to 3). On the other hand, the large-N solution given by equation (35) m isses obviously the sub-leading term of order N⁰, and is therefore inaccurate at sm all N.

The behaviour of the quasi-particle weight close to the transition can be obtained by expanding the energy to next order in , taking into account that $^2_{N=2}_{q}$ (1) $\mathfrak{F}=\mathfrak{F}_{c2}$)^q (so that only the term s with q = 0; 1 m atter). This yields:

$$Z = 1 \frac{U}{U_{c2}} +$$
 (56)

W e note that there are no 1=N prefactors in this expression when couplings are scaled properly.

 $\left(\frac{N}{2}\right)$ (52) atom ic lim it. he variational it not always lower energy l coupling, we to U_{c2} , only N=2 1 m at-N=2 1 = ,) denote terms st that goexistence regim e, in contrast to the exact results esth the trivial to conclude that $U_{c1} = 0$. A nother criterion would be to nd at which coupling the optical gap of the insulator vanishes. Unfortunately, the above approximation (condensed bosons) is insulcient to discuss high-energy features (Hubbard bands). Studies that go beyond this approximation [29] and incorporate uctuations of the slave boson suggest that the optical gap closes at U_{c2} : in that sense the slave boson approximation does not yield M=1 (which are the generic situation within DM FT).

V. FINITE TEM PERATURE TRANSITIONS

We conclude this paper by addressing the nitetem perature aspects of the transitions discussed above. As in the one-band case, we expect a coexistence re- U_{c2} (T) at nite temperature, gion U_{c1} (T) U which closes at a second-order (liquid-gas) critical point (U_M IT; T_M IT), with U_{c1} (T_{M IT}) = U_{c2} (T_{M IT}) = U_{M IT}. Comparison of free-energies then yield a rst-order transition line T = T_c (U) for T < T_M $_{\rm IT}$. This has been the subject of m any studies in the single orbital case, and is now established on m grounds. How ever, no analytical estimate of the critical temperature $T_{M\ II}$ is available. This is highly desirable, since this scale appears to be strongly reduced in comparison to the electronic bandwidth. It would also be interesting to know how this scale depends on the orbital degeneracy.

Let us start with a qualitative argument, which has two merits in our view: (i) it allows to understand why $T_{M II}$ =t is such a small energy scale for a small num – ber of orbitals and (ii) it provides a lower bound on $T_{M II}$. This argument is based on a comparison of the energy di erence between the metallic and insulating solutions at T = 0, to the corresponding entropy di erence. For U = N \mathfrak{G} close to U_{c2}, the energy di erence $E_0 = E_I (T = 0) = E_M (T = 0)$ is expected to behave as:

$$E_0 = N \frac{(\Phi_{c2} \oplus)^2}{\Phi_{c2}} +$$
 (57)

This is indeed supported by the slave-boson calculation of Sec.IV. The entropy di erence $S=S_{\rm I}\ S_{\rm M}$ is dom – inated by the entropy of the insulating solution (which has a degenerate ground-state) since the entropy of the m etal vanishes linearly with T at low temperature T. Therefore:

$$S_0 \ln \frac{N}{N=2}$$
 N ln 2 (58)

This allows to estimate the behaviour of the st-order critical line $U_c(T)$ (or $T_c(U)$) at low-temperature (i.e for U close to U_{c2}). Indeed, the transition into the insulating state upon raising temperature occurs when the entropic gain overcom es the energy cost, leading to:

$$T_{c}(U) \prime \frac{(\Phi_{c2} \Phi)^{2}}{\Phi_{c2}}$$
 (59)

This estimate is valid only at very low temperature, close to the T = 0 critical point $U = U_{c2}$. It indicates a quadratic dependence of the critical line, with a prefactor which is independent of N [30].

W hen U_{c1} is close to U_{c2} , which is the case for a small number of orbitals (in particular in the one-band case), one can roughly estimate the critical endpoint $T_{M II}$ by using (59) in the regime of couplings where the insulating solution disappears, leading to: $T_{\rm M\ IT}$ ' $(\mathfrak{G}_{c2} \quad U_{c1}=N)^2 = \mathfrak{G}_{c2}$. It is clear from this formula that the ratio $T_{M II}$ =t is small because of the small energy di erence between the metallic and insulating solutions. For a larger number of orbitals how ever, this can only produce a lower bound on the critical endpoint $T_{\mbox{\scriptsize M}\xspace{1.5mu}}$. Indeed, the energy di erence close to $T_{M II}$ is certainly underestimated by (57), while the entropy di erence is reduced as compared to N ln 2 since the entropy of the m etal cannot be neglected at $T_{\rm M\ II}$ (we note that it be-/ N). This argum ent shows that haves as T with $T_{\mbox{\scriptsize M}\xspace{1.5}\xspace{1.5}}$ =t m ust either saturate to a constant, or increase with N, as N increases.

We now turn to a more quantitative study of these nite-temperature issues, using the Landau functional form alism introduced in [14]. A functional of the e ective hybridisation is introduced, which reads, for the N - orbitalm odel on the Bethe lattice (sem i-circular d.o.s):

F [] =
$$\frac{N}{2t^2} - \frac{1}{n} (i!_n)^2 + \ln Z_{imp}$$
 [] (60)

in which $Z_{im p}$ is the partition function $Z = Tre^{S_{im p}}$ of the electric in purity model, de ned by the action:

$$S_{imp} = \begin{bmatrix} Z & X & & & \\ & d & d^{+} @ d + \frac{U}{2} & & \\ & & Z & Z & \\ & & + & d & d^{0} & (& {}^{0})^{1} & d^{+} & ()d & ({}^{0}) & (61) \end{bmatrix}$$

This functional is locally stationary for these hybridisation functions which satisfy the DMFT equations:

$$\frac{F}{m} = 0 , \quad (i!_n) = t^2 G (i!_n) \quad (62)$$

The local stability of these DMFT solutions is controlled by the matrix of second derivatives:

$$nm \qquad \frac{{}^{2}F}{(i!_{n}) \quad (i!_{m})} = \frac{N}{t^{2}} + K_{nm} \qquad (63)$$

with, using (60,61):

$$K_{nm} = \frac{1}{2} \frac{R}{P} \int_{1}^{R} d_{1}d_{1}d_{2}d_{2}d_{2}e^{i!_{n}(1)} + i!_{m}(2) +$$

A solution of the DMFT equations is locally stable provided the nm matrix has no negative eigenvalues when evaluated for this solution. Hence, the couplings U_{c1} (T) (resp. U_{c2} (T)) correspond to the instability line of the (U;T) plane along which a negative eigenvalue appears when nm is evaluated for the insulating (resp. metallic) solution. For T = 0, these instability criteria should coincide with those derived from the projective method described above (as veri ed below for U_{c1} (T = 0)). The critical endpoint T = $T_{M IT}$ is such that, for T > $T_{M IT}$, no negative eigenvalue is found, at any coupling U, when the stability matrix is evaluated on the (unique) DMFT solution. It should thus be noted that, in order to determ ine (U_M $_{\rm IT}$;T_M $_{\rm IT}$), it is not necessary to know both $\rm U_{\,c1}$ (T) and $\rm U_{\,c2}$ (T): either one of them $% \rm U_{\,c2}$ is in principle su cient.

The practical di culty in performing this stability analysis at nite temperature is that: (i) it requires a know ledge of the nite-T solution of the DMFT equations -or at least a reasonable approximation to it- and (ii) the two-particle correlator (64) must be evaluated for this solution. C om pleting this program, for arbitrary orbitaldegeneracy, using num ericalm ethods, is beyond the scope of this paper. However, we would like to present here a simpler calculation which gives some insight in the dependence of U $_{c1}$ (T) (and of T $_{\rm M~IT}$) on the orbital degeneracy N . W hat we have done is to use the atom ic lim it as a very rough rst approximation to the insulating solution. W e have evaluated the 2-particle correlator K nm and the stability matrix nm in this limit, for arbitrary N. This can be directly in plemented on the computer, using the spectral decomposition of K $_{\rm nm}\,$ onto atom ic eigenstates (som e details are provided in Appendix B). The stability matrix is then diagonalised numerically (a truncation to a -large-num ber of M atsubara frequencies is made), and we search for the line in the (U;T) plane where a negative eigenvalue is rst found.

The result of this calculation (for the half-lled case n = 1=2) is depicted in Fig.1. There, the temperature below which a negative eigenvalue is found is plotted as a function of U. We rst observe that no instability is

found above a critical value of U, which does coincide with the value (16a): $U_{c1}(T = 0) = t' 4^{r} N + 1$ estim ated above from the projective m ethod (in the atom ic approximation). This is a non-trivial consistency check on our calculations. Secondly, we nd that the instability lines for di erent values of the orbital degeneracy N can all be collapsed on a single curve when both T and U are rescaled by N + 1. This can be understood from the fact that, in the atom ic limit, only the two scales U and T enter the two-particle correlator K nm (not t), and that K is of order N 2 , so that the instability criterion can be written (from dimensionality considera- $\left(\frac{2}{N+1}\right)$. Naturally, we do not expect the tions): $\frac{\mathbf{r}}{\mathbf{t}} =$ curve in Fig. 1 to be a quantitatively reliable determ ination of U_{c1} (T), because of the atom ic approximation involved. In particular, we see that, instead of term inating at a critical endpoint (U $_{\rm M~IT}$;T $_{\rm M~IT}$), the instability line in Fig. 1 bends back, yielding a stability window at small U which is certainly a spurious aspect of the approxim ation. Hence only the branch of the curve corresponding to larger values of U has physical signi cance.

It is ten pting to conclude, from the the observed scaling w ith N + 1, that $T_{M II}$ itself will grow in that m anner as N is increased. Indeed, we note that recent QMC calculations by Am adon and Bierm ann [22] do show a m arked increase of $T_{M \ IT}$ with N , not inconsistent with a N scaling. However, we do not consider this issue to be entirely settled: rather, this atom ic estim ate provides an upper bound on the growth of $T_{M\ IT}$ with N . Indeed, it neglects the presence of the quasiparticle resonance (which is reduced but still present as tem perature is raised close to $T_{M\ II}$). The resonance m akes the solution less stable, so that the atom ic calculation is likely to overestim ate $T_{M \ II}$. C om bined with the above entropy argum ent (which provides a low erbound), we conclude that $T_{M II}$ =t is an increasing function of N at moderate values of N, which either saturates at large-N or increases at most as N. Clearly, a more re ned analysis of the above stability condition is required to settle this issue.

VI. CONCLUSION

In this paper, we have studied the Mott transition of the N -orbital Hubbard model in the fully symmetric case. The physical picture is qualitatively the same as for N = 2, i.e. a coexistence region exists between an insulating and a m etallic solution within two distincts critical couplings U_{c1} and U_{c2}. We have shown that these critical couplings do not have the sam e dependence on the num ber of orbitals, as the latter becom es large: U $_{\rm c1}$ / Ν while U_{c2} / N . We have obtained an exact analytical determ ination of the critical value $\mathfrak{G}_{c2} = U_{c2} = \mathbb{N}$ in this lim it. These results explain the widening of the coexistence window [U_{c1};U_{c2}] observed in the num erical sim ulations of Ref. [21], and more recently in [22]. Our ndings also put the results of R efs. [19, 20] in a new perspective, as discussed in the introduction.

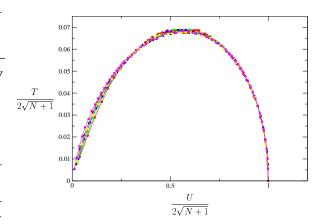


FIG.1: Instability tem perature below which a negative eigenvalue is found when the stability matrix nm of Eq. (63) is evaluated in the atom ic approximation. The various curves are for increasing number of orbitals N = 2;4;6;8;10;20), and an almost perfect scaling with T = N + 1 and U = N + 1 is found.

W e have shown that, at large N and close to the critical coupling U_{c2} , the scaling $U = N \Phi$ is appropriate, so that the separation of scale which is at the heart of the projective method becomes asymptotically exact. The low -energy physics close to U_{c2} is then well described by slave-boson like approxim ations. This is the case in particular for the quasi-particle peak in the spectral function, which is separated from Hubbard bands by a large energy (of order N () and is accurately described by the simple form (32). In view of practical applications to electronic structure calculations with large orbital degeneracy (e.g. f-electron system s), it would be highly desirable to have also an analytical determ ination of the highenergy part of the spectral function in the large-N lim it (or at least reasonable approxim ations to it). This is left for future investigations.

A nother issue that we have only partly addressed is the nite-tem perature aspects of these transitions. The whole nite-tem perature coexistence region widens as N is increased, and the critical tem perature associated with the M ott critical endpoint does increase with the num – ber of orbitals at interm ediate values of N . The precise behaviour of $T_{\rm M\ IT}$ =t at large N deserves further studies how ever.

A cknow ledgm ents

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APPENDIX A:LARGE-N SCALINGSAND THE ATOM IC LIM IT

In this appendix, we provide a detailed proof that the corrections in $V_{\rm H}$ to the atom ic lim it ($V_{\rm H}=0$) do not modify the large-N dependence of the critical couplings. This is done by an explicit investigation of the structure of these corrections. Moreover, we show that for U / N (i.e when $U_{\rm c2}$ is considered), these corrections only produce subdom inant terms which can be ignored at large-N .

1. Corrections in V_H for U = N.

For our purpose, the operator H $_{\rm H}$ can be written :

$$H_{H} = H_{H}^{0} + H_{H}^{1}$$

$$H_{H}^{0} = X_{k}c_{k;}^{y}c_{k;} + \frac{U}{2} X_{k}^{y}(d^{y}d n)$$

$$H_{H}^{1} = V_{H} C_{k;}^{y}d + d^{y}c_{k;}$$
(A1)

F irst let us consider the ground state energy E_{gs} . As the lower H ubbard band H is $\frac{1}{P}$ led in j j, we prefer to rem ove the constant contribution $_{k2H}$; k, so that the zeroth order energy is $E_0 = _0h$ jH $_H^0$ j i $_0 = 0$. The next order term $E_1 = _0h$ jH $_H^1$ j i $_0$ is zero by conservation of the total charge Q on the d-level, so we need to look at the second order contribution:

$$E_{2} = \begin{pmatrix} X & h & jH_{H}^{1} j i_{0}^{2} \\ & & E_{0} & E \end{pmatrix}$$

$$= (N Q) \begin{pmatrix} X & V_{H}^{2} \\ & & E_{0} \end{pmatrix} (A 2)$$

$$= (N Q) \begin{pmatrix} X & V_{H}^{2} \\ & & E_{0} \end{pmatrix} (A 2)$$

since j i can only possess a charge Q + 1 (resp. Q) 1) for the d-electron and a hole (resp. particule) excitation in the bath. Clearly as k is negative (positive) for $k \ 2 \ H$ (H⁺), the denom inators are of order N (since $U = N \hat{F}$) and E_2 is therefore scaling as N⁰ at large N.Wewould like to infer this to be true at all order in the developem ent in $V_{\rm H}$. One can easily classify into two categories the interm ediate states that appear at order V_{H}^{4} and beyond. There can either be a charge di erent form Q on the impurity (as in the previous computation at order $V_{\rm H}^2$) and then the denom inator coming from this state provides (at least) a factor N $^{-1}$ by the presence of the Coulomb energy $U = N \mathfrak{G}$. Or the impurity can be found in a charge Q state (with possibly a reorganization of the spin con quration) without a C oulom b energy cost. However this state possesses also many particlehole excitations in the bath, and this leads to a denom inator which scales as the Mott gap _g. For example let us consider such a ket generated at order $V_{\rm H}^{\,4}$, like

 $j_1:::_Q i_d j_2:::N$ i $j_l i_+$. This particular state (but the argum ent is general), contributes a factor $\begin{pmatrix} k & k^0 \end{pmatrix}^1$ where k 2 H and k^0 2 H⁺. This quantity is always smaller than $_g^{-1}$ because the M ott gap $_g$ is also the gap of the q_k ; electrons (through the self-consistency). As the gap $_g$ is expected to be of order U = N \mathfrak{F} when U is close to U_{c2}, each particle-hole excitation also provides a factor N⁻¹ in the perturbative expansion. This is enough to conclude that, at a given order in perturbation theory, each of the denom inator gives a factor N⁻¹ that balance the combinatorial factor com ing from the string of charge excitation on the inpurity level. Thus E_{gs} is at m ost of order 1 when N is large.

at most of order 1 when N is large. We nally need to compute J^{\circ} at large N. Let us consider rst the case ϵ , so that and will dier by only one spin ip ^{\circ}. We can now calculate at the lowest order in V_H the desired matrix element:

h jd
$$\frac{1}{H_{H}^{0} + H_{H}^{1} - E_{gs}} d^{y}{}_{o}ji$$
 (A3)

with

ji j
$$i_0 + ji_1$$
 (A4)
j $i_1 = \frac{X}{\sum_{k^2H} i_k} \frac{V_H}{\frac{U}{2} - k} d^y c_k; ji_0 + \frac{X}{\sum_{k^2H^+} i_k} \frac{V_H}{\frac{U}{2} + k} c_k^y, dji_0$

The contribution at order $\left(V_{\text{H}}\right)^{0}$ is therefore:

$$_{0} = _{0}h ji \frac{1}{H_{H}^{0} E_{gs}} d^{v}_{o} j i_{0} \frac{2}{U}$$
 (A 5)

because $E_{gs} = 0$ (1) and $U = N \ (1)$. All terms coming at order V_H cancel by conservation of the charge, so we examine now the next leading order for $, _2$, which is composed of three terms: one from the correction by V_H to each of the two external kets, one from the development of the denominator in (A.5) at order V_H^2 , and a mixed term (between only one ket correction and the denominator developed at rst order). Let us examine the rst of these second order contributions:

$${}_{2}^{(1)} = {}_{1}h j d \frac{1}{H_{H}^{0} E_{gs}} d^{y}{}_{0}j \dot{h}$$
 (A 6)

The state d^{y}_{0} j i_{1} is composed of charge Q + 2 excitations (with energy $2^{2}U=2$) and of particle-hole excitations in the bath with a charge Q on the impurity (this has the energy $k = k^{0}$). Both energies scale like N and contribute an overall factor N 3 to $^{(1)}_{2}$. There is also a combinatorial factor of order N coming from the choice in the spin-excitation in j i_{1} , but there is none from the state j i_{1} as the spin con guration in d_{0} j i_{1} is xed by the one in d^{y}_{0} j i_{1} . Therefore $^{(1)}_{2} = O$ (N 2). The same e argument works for the two other contribution at order V_{H}^{2} .

M ore generally, at a given order p in the developm ent in $V_{\rm H}$, each of the p+1 denom inators provides a factor of

order N¹, because there is a nite gap $_{\rm g}$ U_{c2} / N between the two H ubbard bands [25]. However the string of p spin- ips generated by the H_{m ix} terms only contributes to an overall combinatorial factor at most N $^{\rm p=2}$ because one has to connect two xed external con gurations j i and j i. Hence in the lim it of large N all terms after the rst one are sub-dom inant, so that:

$$=$$
 0 + 0 $\frac{1}{N^2}$ $=$ $\frac{2}{U}$ $=$ $\frac{2}{N^{6}}$ (A7)

m eaning that the atom ic result for $\$ is exact in the large- N lim it when U / N .

At this stage, we want to stress a posteriori that the hypotheses m ade in the preceding argument are consistent with this result. First it is correct to x the chem ical potential e = 0 from the atom ic lim it ($V_H = 0$), because perturbative corrections do not change the occupancy of the d-orbital, as can be checked from a direct expansion in V_H of $d^y d$. Finally the existence of a large M ott gap $_g$ / N can also be justi ed on the same grounds.

2. Som e rem arks about $U_{\,{\mbox{cl}}}$

When U / $\frac{p_{N}}{N}$ on the other hand, the perturbative series for does not appear to stop after the rst contribution, showing that U_{c1} is a ected by V_{H} in the large N limit. It is how ever straightforward to follow the line of arguments given in Section IIIC to see that each term in

this development provides a leading contribution of order 1= N (using U g / N). can not be computed exactly in that case, because B (N;n;V_H = (N \mathcal{F})) is now a non trivial function of V_H = \mathcal{F} at N = 1. But this is enough to conclude that B (N;n;V_H = U) is of order 1 at large N when U / N, so that the result U_{c1} N \mathcal{F}_{c1} holds. How ever, an exact evaluation of \mathcal{F}_{c1} appears to be a di cult task, even at N = 1.

APPENDIX B:NUMERICAL CALCULATION OF THE STABILITY MATRIX IN THE ATOM IC LIMIT

In this Appendix, we provide details on the computation of the stability matrix nm in the N-orbital atom ic lim it (cf. Fig. 1). First, we use a spectral decomposition over the atom ic eigenstates in Eq. (64). This yields:

$$K_{nm} = A(i!_n; i!_n; i_n; i_n) = Z_{at} B(i!_n)B(i_n) = Z_{at}^2$$

with

$$Z_{at} = \begin{array}{cc} X^{N} & & N \\ e & e & Q \\ Q = 0 & & Q \end{array}$$

 $A(!_{j}; j = 1::4) \qquad N \qquad \begin{array}{c} X \\ e \\ & E_{0} \\ & P \\ & P$

In these expressions, E_Q U (Q N=2)²=2 are the atom ic energy levels, $_{Q;a}$ E_{Q+a} E_Q , is the signature of the permutation P, and we used the notation f(x_j; j = 1::4) f(x₁; x₂; x₃; x₄). We compute F₄ and F₂, using the relations $!_1 + !_2 + !_3 + !_4 = 0$ and

 $!_1 + !_2 = 0$ respectively. The algorithm can be decom – posed into three functions : (i) From U and T, compute n_m for jnj jn j < 100 and then its lowest eigenvalue $E_0(U;T)$; (ii) Find a point p0 below the instability tem – perature T_i and a majoration T_M of max (T_i) and U_M of U_{c1} ; de ne a path in the (U;T) from (0;0) to (0; T_M) to (U_M ; T_M) to (U_M ;0); (iii) For about 50 points p on this path, solve for $E_0(U;T) = 0$ on the line de ned by p and p_0 using a dichotom y. To speed up the computation, the sum s over permutations and Q in A and B are expanded autom atically into C++ code, which is inlined in the main program. D iagonalisations are perform ed using

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